

CMPDM203NH
SURFACE MOUNT
N-CHANNEL
ENHANCEMENT-MODE
SILICON MOSFET



www.centralsemi.com



SOT-23F CASE

APPLICATIONS:

- Load/Power switches
- Power supply converter circuits
- Battery powered portable equipment

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	12	V
Continuous Drain Current (Steady State)	I_D	3.2	A
Maximum Pulsed Drain Current, $t_p=10\mu\text{s}$	I_{DM}	12.8	A
Power Dissipation	P_D	350	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$
Thermal Resistance	Θ_{JA}	357	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

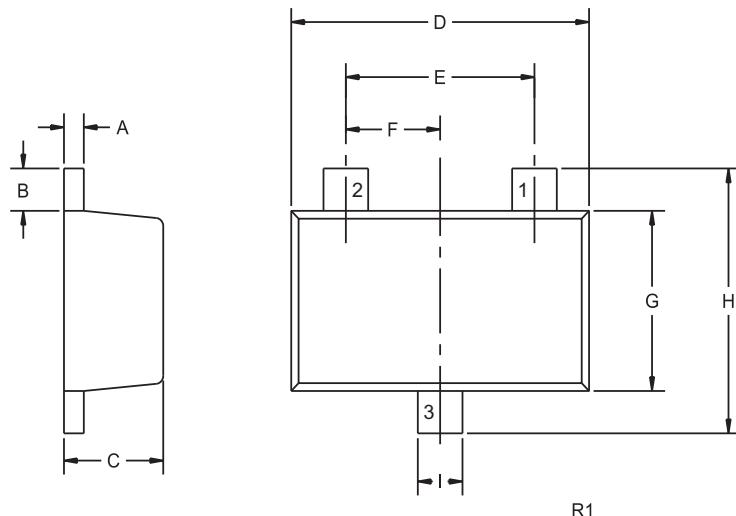
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{GSSF}, I_{GSSR}	$V_{GS}=12\text{V}, V_{DS}=0$			10	μA
I_{DSS}	$V_{DS}=20\text{V}, V_{GS}=0$			1.0	μA
BV_{DSS}	$V_{GS}=0, I_D=250\mu\text{A}$	20			V
$V_{GS(\text{th})}$	$V_{GS}=V_{DS}, I_D=250\mu\text{A}$	0.6		1.2	V
$r_{DS(\text{ON})}$	$V_{GS}=4.5\text{V}, I_D=1.6\text{A}$		0.033	0.05	Ω
$r_{DS(\text{ON})}$	$V_{GS}=2.5\text{V}, I_D=1.6\text{A}$		0.046	0.07	Ω
g_{FS}	$V_{DS}=5.0\text{V}, I_D=3.2\text{A}$		10.5		s
C_{rss}	$V_{DS}=10\text{V}, V_{GS}=0, f=1.0\text{MHz}$	44			pF
C_{iss}	$V_{DS}=10\text{V}, V_{GS}=0, f=1.0\text{MHz}$	395			pF
C_{oss}	$V_{DS}=10\text{V}, V_{GS}=0, f=1.0\text{MHz}$	97			pF
$Q_{g(\text{tot})}$	$V_{DD}=10\text{V}, V_{GS}=4.5\text{V}, I_D=3.2\text{A}$	6.8		10	nC
Q_{gs}	$V_{DD}=10\text{V}, V_{GS}=4.5\text{V}, I_D=3.2\text{A}$	0.8		1.2	nC
Q_{gd}	$V_{DD}=10\text{V}, V_{GS}=4.5\text{V}, I_D=3.2\text{A}$	0.9		1.1	nC
t_{on}	$V_{DD}=10\text{V}, I_D=3.2\text{A}, R_G=10\Omega$	6.0			ns
t_{off}	$V_{DD}=10\text{V}, I_D=3.2\text{A}, R_G=10\Omega$	22.8			ns

R0 (20-October 2010)

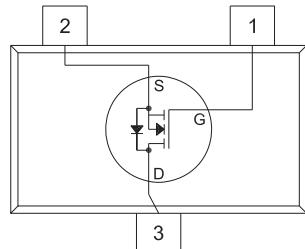
CMPDM203NH
SURFACE MOUNT
N-CHANNEL
ENHANCEMENT-MODE
SILICON MOSFET



SOT-23F CASE - MECHANICAL OUTLINE



PIN CONFIGURATION



SYMBOL	DIMENSIONS			
	INCHES	MMILLIMETERS	MIN	MAX
A	0.004	0.008	0.10	0.20
B	0.012	0.020	0.30	0.50
C	0.031	0.039	0.80	1.00
D	0.110	0.118	2.80	3.00
E	0.075		1.90	
F	0.037		0.95	
G	0.059	0.067	1.50	1.70
H	0.091	0.098	2.30	2.50
I	0.014	0.018	0.35	0.45

SOT-23F (REV: R1)

LEAD CODE:

- 1) Gate
- 2) Source
- 3) Drain

MARKING CODE: 203C

R0 (20-October 2010)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp.
145 Adams Avenue
Hauppauge, NY 11788 USA
Main Tel: (631) 435-1110
Main Fax: (631) 435-1824
Support Team Fax: (631) 435-3388
www.centralsemi.com

Worldwide Field Representatives:
www.centralsemi.com/wwreps

Worldwide Distributors:
www.centralsemi.com/wwdistributors

For the latest version of Central Semiconductor's **LIMITATIONS AND DAMAGES DISCLAIMER**, which is part of Central's Standard Terms and Conditions of sale, visit: www.centralsemi.com/terms